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Substitute for form 1449A/B/PTO				Complete if Known		
				Application Number	Not Yet Assigned 10/699652	
INFORMATION DISCLOSURE				Filing Date	Concurrently Herewith	
STATEMENT BY APPLICANT			PPLICANT	First Named Inventor	Hagop A. Nazarian	
				Art Unit	NA 2827	
(Use as many sheets as necessary)			necessary)	Examiner Name	Not Yet Assigned T. T. Nguye	
Sheet	1	of	1	Attorney Docket Number	M4065.0901/P901	

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